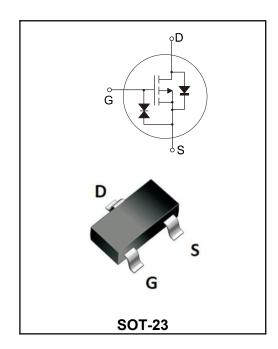


P-Channel MOSFET

Features

- Energy efficient
- Low threshold voltage
- High-speed switching
- Miniature surface mount package saves board space
- ESD protected(HBM) up to 2KV



Marking Code			
BSS84	PD		

Absolute Maximum Ratings (Ta=25℃)

Parameter	Symbol	Maximum	Units			
Drain-Source Voltage	-V _{DS}	50	V			
Gate-Source Voltage	V_{GS}	±20	V			
Continuous Drain Current	-I D	0.13				
Pulsed Drain Current Note1 @tp<10μs	-I DM	0.52	_ ^			
Power Dissipation	P _D	225	mW			
Junction and Storage Temperature Range	T _J , T _{STG}	150, -55 to 150	°C			
Thermal Characteristics						
Parameter	Symbol	Тур.	Units			
Maximum Junction-to-Ambient Note2	RθJA	556	°C/W			



Electrical Characteristics (Ta=25℃ unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Static Parameters						
Drain-Source Breakdown Voltage	-BV _{DSS}	-I _D =250μA, V _{GS} =0V	50	_		٧
Zero Gate Voltage Drain Current	-I _{DSS}	-V _{DS} =50V, V _{GS} =0V	_		1	μA
		-V _{DS} =25V, V _{GS} =0V	_		0.1	μA
Gate-Body Leakage Current	Igss	V _{DS} =0V, V _{GS} =±20V	_	1	5	μΑ
Gate Threshold Voltage Note3	-V _{GS(th)}	V _{DS} =V _{GS} , -I _D =250μA	0.9	1.3	2	V
Static Drain-Source On-Resistance	_	-V _{GS} =10V, -I _D =0.1A	_	1.7	8	Ω
	R _{DS(ON)}	-V _{GS} =5V, -I _D =0.1A	_	1.9	10	Ω
Body Diode Forward Voltage	-V _{SD}	-I _S =0.13A, V _{GS} =0V	_	_	1.2	V
Dynamic Parameters						
Forward Transconductance Note3	g FS	-V _{DS} =25V, -I _D =0.1A	50	_	_	mS
Input Capacitance	Ciss		_	30	_	pF
Output Capacitance	Coss	V _{GS} =0V, -V _{DS} =5V, f=1MHz	_	10	-	pF
Reverse Transfer Capacitance	Crss		_	5	_	pF
Switching Parameters						
Turn-On DelayTime	t _{D(on)}			2.5		ns
Turn-On Rise Time	t _r	-V _{DD} =15V, R _L =50Ω, -I _D =2.5A		1		ns
Turn-Off DelayTime	t _{D(off)}			16		ns
Turn-Off Fall Time	t _f		-	8		ns
Source-Drain Diode characteristics						
Diode forward current	-Is			_	0.13	Α
Diode pulsed forward current	-Іѕм			_	0.52	Α

Notes: 1. Repetitive rating : Pulse width limited by junction temperature.

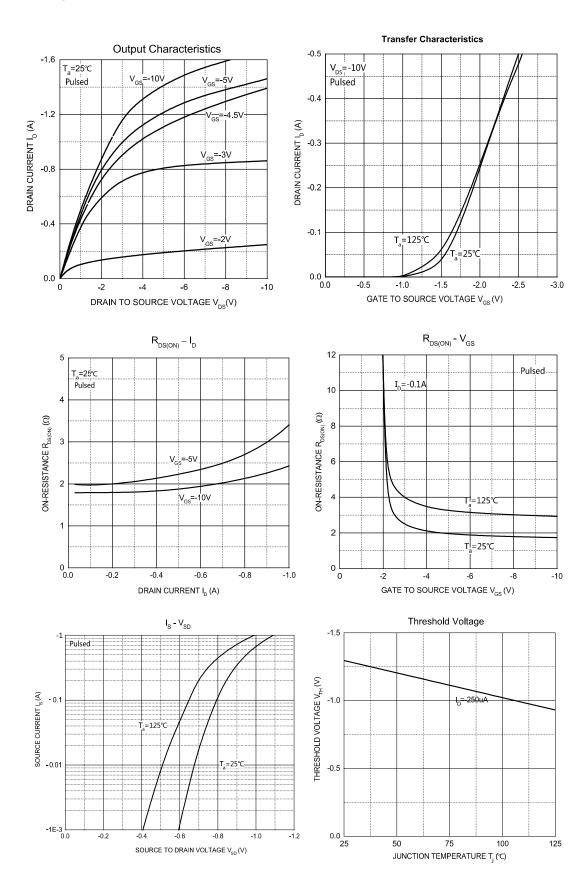
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^{2.} Surface mounted on FR4 board , t \leq 10s.

^{3.} Pulse Test : Pulse Width $\!\!\leqslant\! 300\mu s,$ Duty Cycle $\!\!\leqslant\! 2\%.$



Typical Characteristics



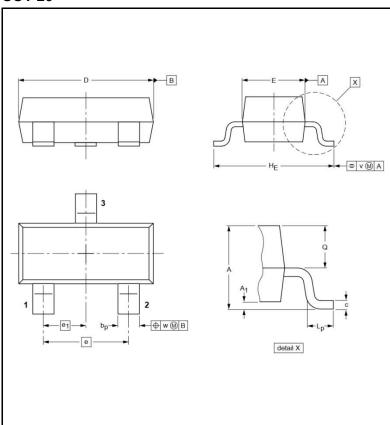


Ordering information

Package	Package Packing Description		Packing Quantity
SOT-23	Tape/Reel,7"reel	3000pcs/Reel	24000PCS/Box 120000PCS/Carton

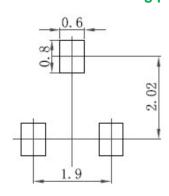
Package Dimensions

SOT-23



Dim.		meter im)	mil		
	Min.	Max.	Min.	Max.	
Α	0.9	1.15	35	45	
A1	0.1		3.9)	
bp	0.38	0.48	15	19	
С	0.09	0.15	3.54	5.9	
D	2.8	3.0	110	118	
E	1.2	1.4	47	55	
Е	1.9		75		
E1	0.95		37	7	
HE	2.1	2.55	83	100	
Lp	0.15	0.45	5.9	18	
Q	0.45	0.55	18	22	
V	0.2		7.9		
W	0.1		4		

The recommended mounting pad size





Disclaimer

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